## NSN 5962-01-449-5825

Memory Microcircuit - Page 1 of 1



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Maximum Power Discination Pating
Maximum Power Dissipation Rating:  1.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-15s
Features Provided:
Electrostatic sensitive and programmed and ultraviolet erasable and burn in
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Input Circuit Pattern:
15 input
Criticality Code Justification:
Cbbl
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
250.00 nanoseconds access
Memory Device Type:
Pal
Special Features:
Altered item make from 8202505ya
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:
No
Fiig:
A458a0